

## 2.0 AMP SURFACE MOUNT HIGH EFFICIENCY RECTIFIERS



### FEATURES

- \* Ideal for surface mount applications
- \* Easy pick and place
- \* Built-in strain relief
- \* Low forward voltage drop

### MECHANICAL DATA

- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Metallurgically bonded construction
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.093 grams

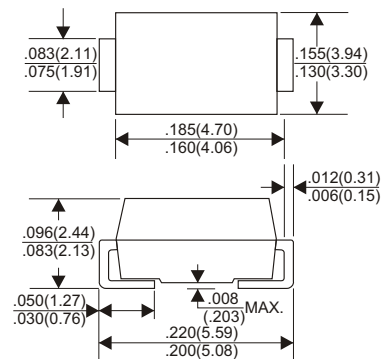
### VOLTAGE RANGE

50 to 1000 Volts

### CURRENT

2.0 Ampere

#### DO-214AA(SMB)



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
 Single phase half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

TYPE NUMBER	US2AB	US2BB	US2DB	US2EB	US2GB	US2JB	US2KB	US2MB	UNITS	
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V	
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V	
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V	
Maximum Average Forward Rectified Current										
.375"(9.5mm) Lead Length at Ta=50°C									2.0	A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)									60	A
Maximum Instantaneous Forward Voltage at 2.0A	1.0		1.3		1.7				V	
Maximum DC Reverse Current Ta=25°C									5.0	μA
at Rated DC Blocking Voltage Ta=100°C									150	μA
Maximum Reverse Recovery Time (Note 1)	50				70				nS	
Typical Junction Capacitance (Note 2)									30	pF
Operating and Storage Temperature Range Tj, Tstg									-65 — +150	°C

#### NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

## RATING AND CHARACTERISTIC CURVES (US2AB THRU US2MB)

FIG.1-TYPICAL FORWARD CHARACTERISTICS

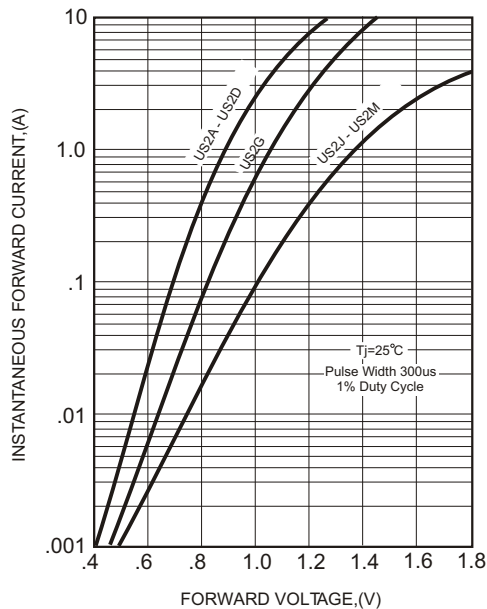


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

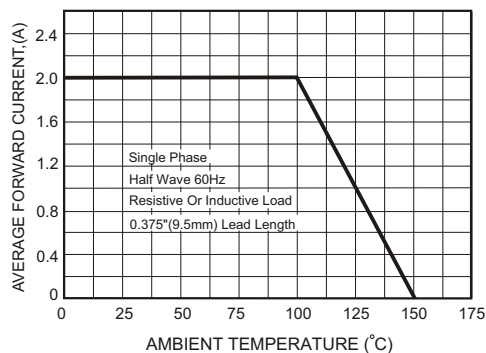


FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

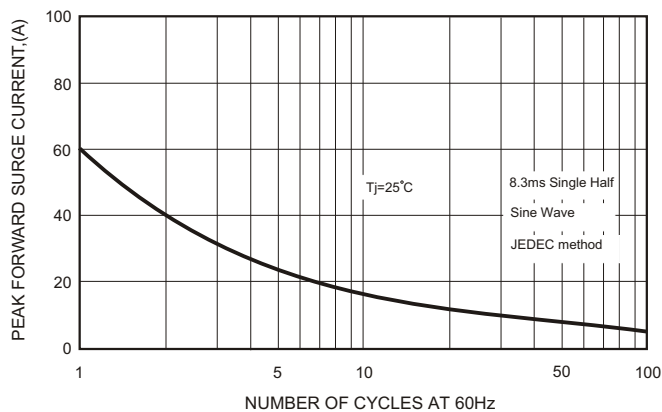
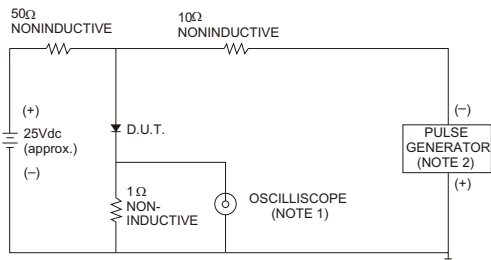


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time= 7ns max., Input Impedance= 1 megohm.22pF.

2. Rise Time= 10ns max., Source Impedance= 50 ohms.

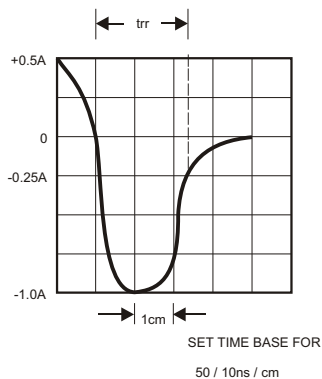


FIG.5-TYPICAL JUNCTION CAPACITANCE

